NSN 5961-01-041-1554

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-041-1554 **Inclosure Material:** Metal **Overall Length:** Between 0.235 inches and 0.300 inches Overall Diameter: Between 0.490 inches and 0.510 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter reverse voltage, with base short-circuited to emitter and 50.0 collector to emitter reverse voltage and 33.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No